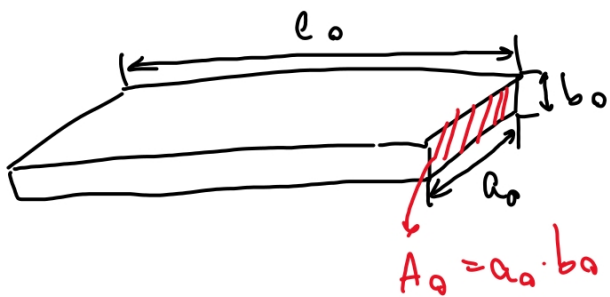


# Seminar 1 SIS:

## Marca tensometrică (strain gage).

sensibilitatea  $S = \frac{\frac{\Delta R}{R_0}}{\frac{\Delta l}{l_0}}$  ("gage factor").



$a_0, b_0, l_0, R_0 \rightarrow$  mărcii în stare nedeformată,

coef. Poisson:  $\mu = - \frac{\frac{\Delta a}{a_0}}{\frac{\Delta l}{l_0}} = - \frac{\frac{\Delta b}{b_0}}{\frac{\Delta l}{l_0}}$

constantă de material:  $k$ .  
rezistivitatea,  $\rho$

$$R = \rho \cdot \frac{l}{A}$$

$$\frac{1}{R_0} = \frac{A_0}{\rho_0 \cdot l_0}$$

$$\Delta R = \Delta \rho \cdot \frac{l_0}{A_0} + \frac{\rho_0}{A_0} \cdot \Delta l + \rho_0 \cdot l_0 \cdot \Delta \left( \frac{1}{A} \right) =$$

$$= \Delta \rho \cdot \frac{l_0}{A_0} + \Delta l \cdot \frac{\rho_0}{A_0} - \frac{1}{A_0^2} \cdot \Delta A \cdot \rho_0 \cdot l_0 \quad \Bigg| \cdot \frac{1}{R_0}$$

$$\frac{\Delta R}{R_0} = \Delta \rho \cdot \frac{l_0}{A_0} \cdot \frac{A_0}{\rho_0 \cdot l_0} + \Delta l \cdot \frac{\rho_0}{A_0} \cdot \frac{A_0}{\rho_0 \cdot l_0} - \frac{1}{A_0} \cdot \frac{\rho_0 \cdot l_0}{A_0} \cdot \frac{A_0}{\rho_0 \cdot l_0} \cdot \Delta A$$

$$\left| \frac{\Delta R}{R_0} = \frac{\Delta \rho}{\rho_0} + \frac{\Delta l}{l_0} - \frac{\Delta A}{A_0} \right| *$$

$$\frac{\Delta A}{A_0} = \frac{\Delta a \cdot b_0}{a_0 b_0} + \frac{\Delta b \cdot a_0}{a_0 b_0} = \frac{\Delta a}{a_0} + \frac{\Delta b}{b_0}$$

$$\mu = - \frac{\frac{\Delta a}{a_0}}{\frac{\Delta l}{l_0}} = - \frac{\frac{\Delta b}{b_0}}{\frac{\Delta l}{l_0}}$$

$$A = a \cdot b$$

$$A_0 = a_0 \cdot b_0$$

$$\left| \frac{\Delta A}{A_0} = -2\mu \cdot \frac{\Delta l}{l_0} \right| **$$

$$*, ** \Rightarrow \frac{\Delta R}{R_0} = \frac{\Delta l}{l_0} + 2\mu \frac{\Delta l}{l_0} + \frac{\Delta \rho}{\rho_0}$$

$$\frac{\Delta R}{R_0} = (1 + 2\mu) \frac{\Delta l}{l_0} + \frac{\Delta \rho}{\rho_0}$$

In metals  $\frac{\Delta \rho}{\rho_0}$  e negligibil  $\Rightarrow$

$$\Rightarrow S = \frac{\frac{\Delta R}{R_0}}{\frac{\Delta \rho}{\rho_0}} \approx 1 + 2\mu$$

pt. metale,  $\mu \approx 0.3 - 0.4 \Rightarrow$

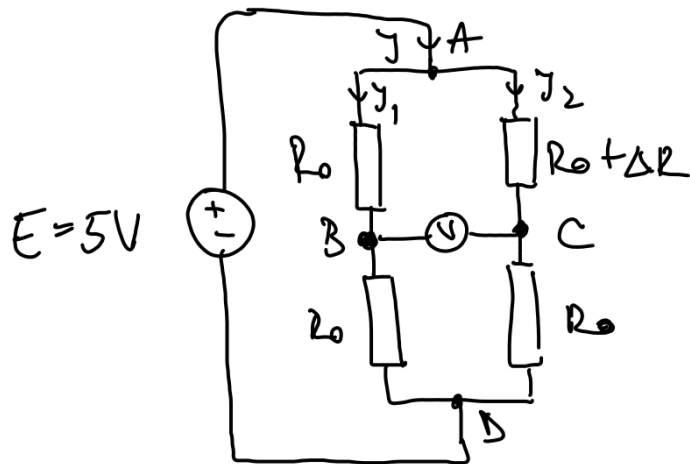
$$\Rightarrow \boxed{S \approx 2.1}$$

pt. semiconductori  $S = 100$

Traductor de deformare:

marca tensometrică:  $R_0 = 120 \Omega$   
 $\Delta R = 0.1 \Omega.$

$$S = ? \quad (V/\Omega)$$

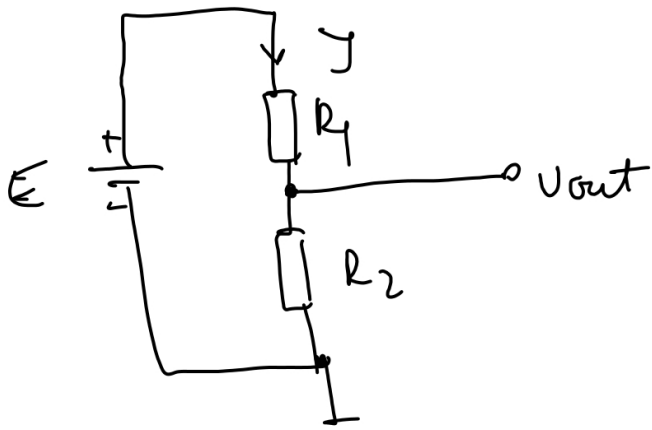


$$E = V_B - V_C$$

$$E = U_{BD} - U_{CD}.$$

$$U_{BD} = 2.5V$$

$$E = U_{AC} + U_{CD} = I_2 (R_0 + \Delta R + R_0)$$



$$E = I(R_1 + R_2)$$

$$V_{out} = I \cdot R_2$$

$$V_{CD} = I_2 \cdot R_0$$

$$\frac{V_{CD}}{E} = \frac{I_2 R_0}{I_2 (R_0 + \Delta R + R_0)}$$

$$V_{CD} = E \cdot \frac{R_0}{2R_0 + \Delta R}$$

$$\Sigma = \frac{E}{2} - E \frac{R_0}{2R_0 + \Delta R}$$

OUT  $\rightarrow \Sigma$   
IN  $\rightarrow \Delta R$

$$\Delta R_{min} = 0$$

$$\Delta R_{max} = 0.1$$

$$\Sigma_{min} = ?$$

$$\Sigma_{max} = ?$$

$$S = \frac{\Sigma_{max} - \Sigma_{min}}{\Delta R_{max} - \Delta R_{min}} = ?$$